Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.380 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 regulator voltage

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

100.00 milliamperes all primaries horsepower metric and 400.00 milliamperes repetitive peak forward current

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/114 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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